Diode Semiconductor Device - Page 1 of 1



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Inc	losure Material:
Gla	ass
Ov	erall Length:
0.3	300 inches
Те	rminal Length:
0.5	i00 inches
٥v	erall Diameter:
0.1	07 inches
En	d Application:
An	/gsq-207v1
Jo	int Electronic Device Engineering Council/jedec/case Outline Designation:
Do	-7
Мо	ounting Method:
Те	rminal
Fea	atures Provided:
He	rmetically sealed case
Se	miconductor Material:
Sili	con
Vo	Itage Rating In Volts Per Characteristic:
5.0	regulator voltage
Cu	rrent Rating Per Characteristic:
70.	00 milliamperes repetitive peak forward current
Ро	wer Rating Per Characteristic:
400	0.0 milliwatts small-signal input power, common-collector preset
Ма	ximum Operating Tempurature Per Measurement Point:
17	5.0 degrees celsius junction
Те	rminal Type And Quantity:
2 u	ininsulated wire lead
Sh	elf Life:
N/a	a
Un	it Of Measure:
De	militarization:
No	
Fii	g:
	10a0